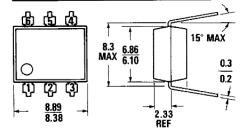
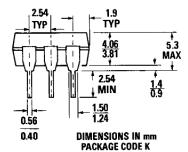


MICROPROCESSOR COMPATIBLE GAAS SCHMITT TRIGGER OPTOCOUPLERS

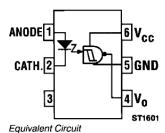
H11L1 H11L2 H11L3

PACKAGE DIMENSIONS





ST1603A



TOTAL PACKAGE

DESCRIPTION

The H11L series has a medium-to-high speed integrated circuit detector optically coupled to a gallium-arsenide infrared emitting diode. The output incorporates a Schmitt trigger, which provides hysteresis for noise immunity and pulse shaping. The detector circuit is optimized for simplicity of operation and utilizes an open collector output for maximum application flexibility.

FEATURES

- High data rate, 1 MHz typical (NRZ)
- Free from latch up and oscillation throughout voltage and temperature ranges.
- Microprocessor compatible drive
- Logic compatible output sinks 16 mA at 0.4 V maximum
- Guaranteed on/off threshold hysteresis
- High common mode rejection ratio
- Fast switching: t_r, t_t=100 ns typical
- Wide supply voltage capability, compatible with all popular logic systems
- Underwriters Laboratory (UL) recognized file #E90700

* APPLICATIONS

- Logic to logic isolator
- Programmable current level sensor
- Line receiver—eliminate noise and transient problems
- A.C. to TTL conversion—square wave shaping
- Digital programming of power supplies
- Interfaces computers with peripherals

ABSOLUTE MAXIMUM RATINGS

DETECTOR

DETECTOR
Power dissipation (at 25°C ambient) 150 mW
Derate linearly (above 25°C ambient) 2 mW/°C
V ₄₅ allowed range 0 to 16 V
V₅s allowed range 0 to 16 V
Loutout current 50 mA



MICROPROCESSOR COMPATIBLE GAAS SCHMITT TRIGGER OPTOCOUPLERS

ELECTRICAL CHARACTERISTICS (T_A= 0-70°C Unless Otherwise Specified)

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
INPUT DIODE						
Forward voltage	V _F		1.1	1.5	V	$I_F = 10 \text{ mA}$
	V _F	0.75	0.95		V	I _F =0.3 mA
Reverse current	I _R			10	μΑ	V _R =3 V
Capacitance	C,			100	pF	V=0, f=1 MHz
OUTPUT DETECTOR Operating voltage range	V _{cc}	3		15	V	
Supply current	I _{6(off)}		1.0	5.0	mA	I _F =0, V _{CC} =5 V
Output current, high	I _{OH}		***	100	μA	I _F =0, V _{CC} =V _C =15 V

CHARACTERISTIC	;	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
Supply current		l _{6(on)}		1.6	5	mA	I _F =10 mA, V _{cc} =5 V
Output voltage, low		Vol		0.2	0.4	٧	R_L =270 Ω , V_{CC} =5 V , I_F = $I_{F(on)}$ max.
Turn-on threshold current	(H11L1)	I _{F(on)}		1.0	1.6	mA	R _L =270 Ω, V _{cc} =5 V
	(H11L2)	I _{F(on)}		6.0	10.0	mA	R _L =270 Ω, V _{CC} =5 V
	(H11L3)	I _{F(on)}		3.0	5.0	mA	R _L =270 Ω, V _{cc} =5 V
Turn-off threshold current		I _{F(off)}	0.3	1.0		mA	R _L =270 Ω, V _{cc} =5 V
Hysteresis ratio		$I_{F(off)}/I_{F(on)}$	0.50	0.75	0.90	-	R ₁ =270 Ω, V _{cc} =5 V



MICROPROCESSOR COMPATIBLE GAAS SCHMITT TRIGGER OPTOCOUPLERS

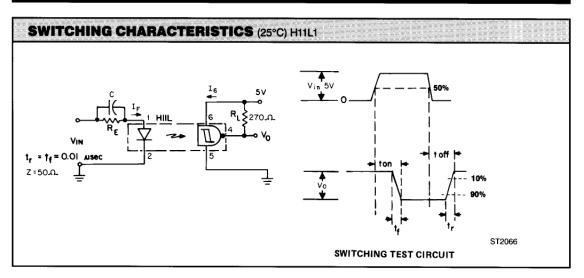
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
SWITCHING SPEED Turn-on time	t _{on}		1.0		μS	$C=0$, $R_E=1.2 \text{ k}\Omega$
	t _{on}		0.65		μS	C=270 pF, R _E =1.2 kΩ f≤100 KHz, tp≥1 μs
Fall time	t,		0.1		μS	$C=0,R_{\epsilon}=1.2 \text{ k}\Omega$
	t,		0.05		μS	C=270 pF, R _E =1.2 k Ω f≤100 KHz, tp≥1 μ s
Turn-off time	t _{off}		2.0		μS	$C=0,R_E=1.2 \text{ k}\Omega$
	t _{OFF}		1.20		μS	C=270 pF, R _E =1.2 kΩ f≤100 KHz, tp≥1 μs
Rise time	t,		0.1	1.00	μS	C=0,R _E =1.2 kΩ
	t,		0.07		μS	C=270 pF, R _E =1.2 kΩ f≤100 KHz, tp≥1 μs
Data rate			1.0*		MHz	

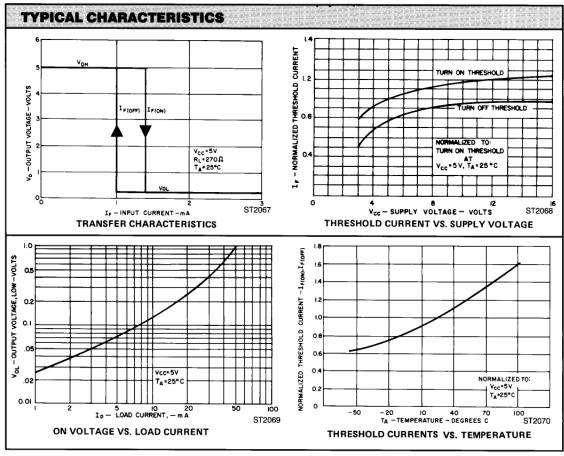
ISOLATION CHA	RACTERIST	ICS				
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
Surge isolation voltage	V _{ISO}	7500			V_{PEAK}	1 Minute
Surge isolation voltage	V _{iso}	5300	-		V _{RMS}	1 Minute

^{*}Maximum data rate will vary depending on the bias conditions and is usually highest when R_ϵ and C are matched to $I_{r_{(ON)}}$ and V_{cc} is between 3 and 15 V. With this optimized bias, most units will operate over 1.5 MHz (NRZ).



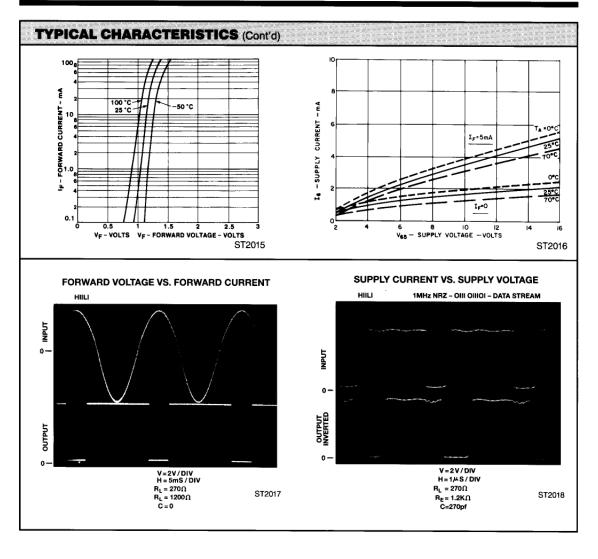
MICROPROCESSOR COMPATIBLE GaAs SCHMITT TRIGGER OPTOCOUPLERS





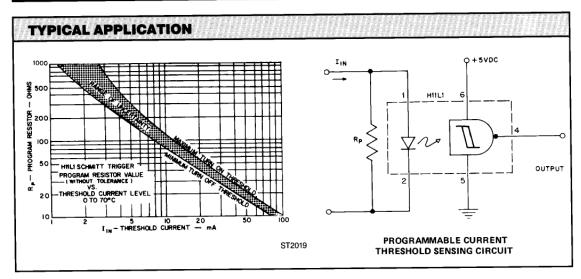


MICROPROCESSOR COMPATIBLE GaAs SCHMITT TRIGGER OPTOCOUPLERS





MICROPROCESSOR COMPATIBLE GaAs SCHMITT TRIGGER OPTOCOUPLERS





MICROPROCESSOR COMPATIBLE GaAs SCHMITT TRIGGER OPTOCOUPLERS

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- A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.